



## MM5871 rhythm pattern generator

### general description

The MM5871 rhythm pattern generator is an MOS/LSI circuit, fabricated with P-channel enhancement-mode and ion-implanted, depletion-mode devices. The PLA implementation is programmed to produce 6 rhythm patterns which may be combined in any manner and provide 5 instrument-trigger outputs. Trigger output pulse width is determined by an external RC network, (Figure 1). A similar network, including a potentiometer, determines tempo of the on-chip oscillator. This circuit is packaged in a 16-pin Epoxy-B DIP, (Figure 2). Figure 3 illustrates the standard pattern coding. Figure 4 is a programming worksheet for ordering custom patterns.

- 5 trigger outputs
- Flexible supply voltages
- Low power dissipation

### standard patterns

- Waltz (3/4)
- Swing (3/4)
- Country/Western (3/4)
- March (4/4)
- Latin (4/4)
- Rock (4/4)

### features

- On-chip tempo oscillator
- Variable output pulse width
- 6 rhythm patterns

### applications

- Electronic organs
- Portable rhythm boxes

### block and connection diagrams

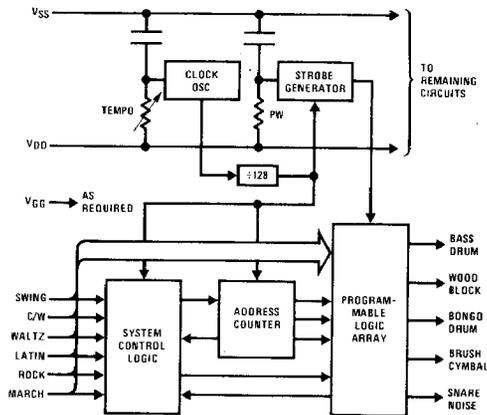


FIGURE 1.

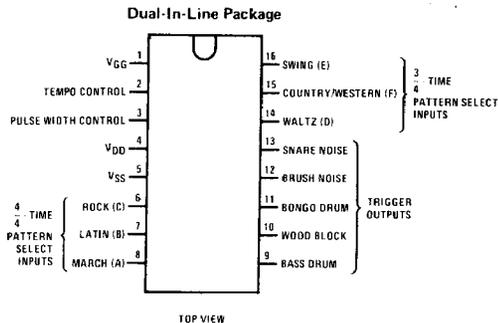


FIGURE 2.

Order Number MM5871N  
See Package 19

## absolute maximum ratings

		MIN	MAX	UNITS
Supply Voltages	V <sub>GG</sub>	-33	0.3	V
	V <sub>DD</sub>	-22	0.3	V
Input Voltage		-18	0.3	V
Storage Temperature	T <sub>S</sub>	-55	100	°C
Operating Temperature	T <sub>A</sub>	0	70	°C
Lead Temperature (Soldering, 10 seconds)			300	°C

## electrical characteristics

T<sub>A</sub> within operating range, V<sub>SS</sub> = 0V, V<sub>DD</sub> = -14V ±2V, V<sub>GG</sub> = -27V ±2V, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Tempo Control Input	C to V <sub>SS</sub> = 0.0056 μF				
Minimum Tempo	R to V <sub>DD</sub> = 1.1 MΩ	≤2.7			bps
Maximum Tempo	R to V <sub>DD</sub> = 120 kΩ (Note 1)			≥27	bps
Pulse Width Control Input	C to V <sub>SS</sub> = 0.0056 μF				
	R to V <sub>DD</sub> = 100 kΩ, (Note 1)	2	3	4	ms
Select Inputs					
Logic High Level	(Active Level)	V <sub>SS</sub> -0.75	V <sub>SS</sub>	V <sub>SS</sub> +0.3	V
Input Current	V <sub>IH</sub> = V <sub>SS</sub>			0.2	mA
Logic Low Level		V <sub>DD</sub>	V <sub>DD</sub>	V <sub>DD</sub> +0.75	V
Trigger Outputs					
Logic High Level	(Active Level) (w/20k to V <sub>DD</sub> )	V <sub>SS</sub> -0.37		V <sub>SS</sub> +0.3	V
Leakage Current	V <sub>OL</sub> = V <sub>DD</sub> , (Note 2)			-10	μA
Supply Currents	(No Output Loads)				
	I <sub>DD</sub>			20	mA
	I <sub>GG</sub>			5	mA

**Note 1:** Both the Tempo Control and Pulse Width Control inputs utilize external RC networks to determine tempo and strobe pulse width. Additionally, these parameters are affected by the V<sub>SS</sub> - V<sub>DD</sub> voltage. Therefore, for these tests the RC values apply to V<sub>SS</sub> - V<sub>DD</sub> = -14 ±0.5 volts.

**Note 2:** All trigger outputs are open-drain transistors. The active output level is therefore high, and the off condition is high impedance as indicated by the specified leakage current.

